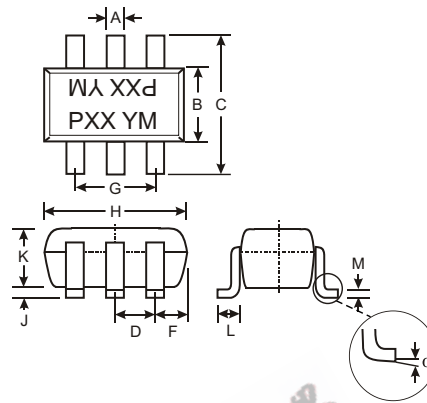


Features

- Epitaxial Planar Die Construction
- Built-In Biasing Resistors

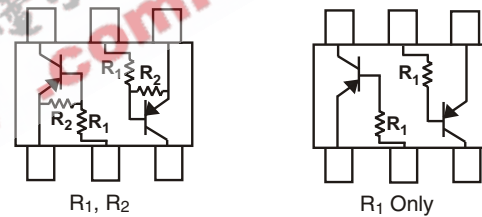
Mechanical Data

- Case: SOT-363, Molded Plastic
- Case material - UL Flammability Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020A
- Terminals: Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking: Date Code and Marking Code (See Diagrams & Page 3)
- Weight: 0.006 grams (approx.)
- Ordering Information (See Page 3)



SOT-363		
Dim	Min	Max
A	0.10	0.30
B	1.15	1.35
C	2.00	2.20
D	0.65 Nominal	
F	0.30	0.40
H	1.80	2.20
J	—	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.25
α	0°	8°
All Dimensions in mm		

P/N	R1	R2	MARKING
DDA124EU	22KΩ	22KΩ	P17
DDA144EU	47KΩ	47KΩ	P20
DDA114YU	10KΩ	47KΩ	P14
DDA123JU	2.2KΩ	47KΩ	P06
DDA114EU	10KΩ	10KΩ	P13
DDA143TU	4.7KΩ	-	P07
DDA114TU	10KΩ	-	P12



SCHMATIC DIAGRAM

Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Supply Voltage, (3) to (1)	V _{CC}	50	V
Input Voltage, (2) to (1)	V _{IN}	DDA124EU: +10 to -40 DDA144EU: +10 to -40 DDA114YU: +6 to -40 DDA123JU: +5 to -12 DDA114EU: +10 to -40 DDA143TU: +5 V _{max} DDA114TU: +5 V _{max}	V
Output Current	I _O	DDA124EU: -30 DDA144EU: -30 DDA114YU: -70 DDA123JU: -100 DDA114EU: -50 DDA143TU: -100 DDA114TU: -100	mA
Output Current	I _C (Max)	-100	mA
Power Dissipation (Total)	P _d	200	mW
Thermal Resistance, Junction to Ambient Air (Note 1)	R _{θJA}	625	°C/W
Operating and Storage and Temperature Range	T _J , T _{STG}	-55 to +150	°C

- Note: 1. Mounted on FR4 PC Board with recommended pad layout at <http://www.diodes.com/datasheets/ap02001.pdf>.
2. 150mW per element must not be exceeded.

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic (DDA143TU & DDA114TU only)	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	-50	—	—	V	$I_C = -50\mu\text{A}$
Collector-Emitter Breakdown Voltage	BV_{CEO}	-50	—	—	V	$I_C = -1\text{mA}$
Emitter-Base Breakdown Voltage	BV_{EBO}	-5	—	—	V	$I_E = -50\mu\text{A}$
Collector Cutoff Current	I_{CBO}	—	—	-0.5	μA	$V_{CB} = -50\text{V}$
Emitter Cutoff Current	I_{EBO}	—	—	-0.5	μA	$V_{EB} = -4\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	—	—	-0.3	V	$I_C/I_B = -2.5\text{mA} / -0.25\text{mA}$ DDA143TU $I_C/I_B = -1\text{mA} / -0.1\text{mA}$ DDA114TU
DC Current Transfer Ratio	h_{FE}	100	250	600	—	$I_C = -1\text{mA}, V_{CE} = -5\text{V}$
Input Resistor (R_1) Tolerance	ΔR_1	-30	—	+30	%	—
Gain-Bandwidth Product*	f_T	—	250	—	MHz	$V_{CE} = -10\text{V}, I_E = 5\text{mA}, f = 100\text{MHz}$

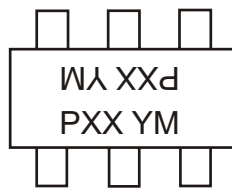
Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	DDA124EU DDA144EU DDA114YU DDA123JU DDA114EU	$V_{I(off)}$	-0.5 -0.5 -0.3 -0.5 -0.5	-1.1 -1.1 — — -1.1	—	—	$V_{CC} = -5\text{V}, I_O = -100\mu\text{A}$
	DDA124EU DDA144EU DDA114YU DDA123JU DDA114EU	$V_{I(on)}$	—	— -1.9 -1.9 — -1.9	-3.0 -3.0 -1.4 -1.1 -3.0	V	$V_O = -0.3, I_O = -5\text{mA}$ $V_O = -0.3, I_O = -2\text{mA}$ $V_O = -0.3, I_O = -1\text{mA}$ $V_O = -0.3, I_O = -5\text{mA}$ $V_O = -0.3, I_O = -10\text{mA}$
Output Voltage	DDA124EU DDA144EU DDA114YU DDA123JU DDA114EU	$V_{O(on)}$	—	-0.1	-0.3	V	$I_O/I_I = -10\text{mA} / -0.5\text{mA}$ $I_O/I_I = -10\text{mA} / -0.5\text{mA}$ $I_O/I_I = -5\text{mA} / -0.25\text{mA}$ $I_O/I_I = -5\text{mA} / -0.25\text{mA}$ $I_O/I_I = -10\text{mA} / -0.5\text{mA}$
Input Current	DDA124EU DDA144EU DDA114YU DDA123JU DDA114EU	I_I	—	—	-0.36 -0.18 -0.88 -3.6 -0.88	mA	$V_I = -5\text{V}$
Output Current		$I_{O(off)}$	—	—	-0.5	μA	$V_{CC} = -50\text{V}, V_I = -0\text{V}$
DC Current Gain	DDA124EU DDA144EU DDA114YU DDA123JU DDA114EU	G_I	56 68 68 80 30	—	—	—	$V_O = -5\text{V}, I_O = -5\text{mA}$ $V_O = -5\text{V}, I_O = -5\text{mA}$ $V_O = -5\text{V}, I_O = -10\text{mA}$ $V_O = -5\text{V}, I_O = -10\text{mA}$ $V_O = -5\text{V}, I_O = -5\text{mA}$
Input Resistor (R_1) Tolerance		ΔR_1	-30	—	+30	%	—
Resistance Ratio Tolerance		R_2/R_1	-20	—	+20	%	—
Gain-Bandwidth Product*		f_T	—	250	—	MHz	$V_{CE} = -10\text{V}, I_E = -5\text{mA}, f = 100\text{MHz}$

* Transistor - For Reference Only

Ordering Information (Note 3)

Device	Packaging	Shipping
DDA124EU-7	SOT-363	3000/Tape & Reel
DDA144EU-7	SOT-363	3000/Tape & Reel
DDA114YU-7	SOT-363	3000/Tape & Reel
DDA123JU-7	SOT-363	3000/Tape & Reel
DDA114EU-7	SOT-363	3000/Tape & Reel
DDA143TU-7	SOT-363	3000/Tape & Reel
DDA114TU-7	SOT-363	3000/Tape & Reel

Notes: 3. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information

PXX = Product Type Marking Code
 See Sheet 1 Diagrams
 YM = Date Code Marking
 Y = Year ex: N = 2002
 M = Month ex: 9 = September

Date Code Key

Year	2002	2003	2004	2005	2006	2007	2008	2009
Code	N	P	R	S	T	U	V	W

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

TYPICAL CURVES - DDA123JU
ONE SECTION

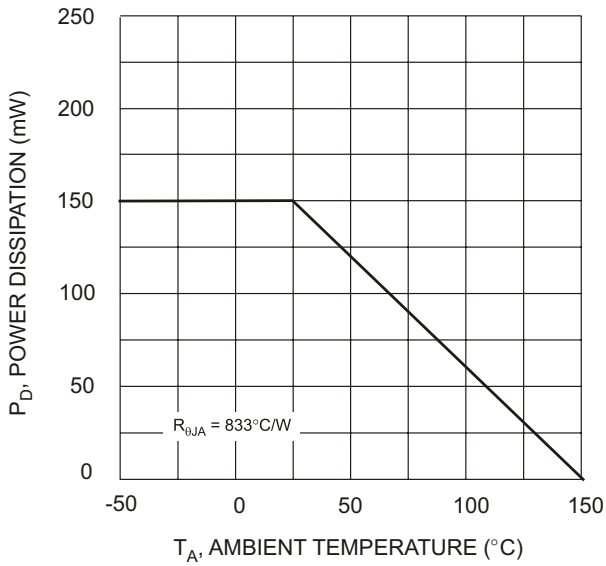


Fig. 1 Derating Curve

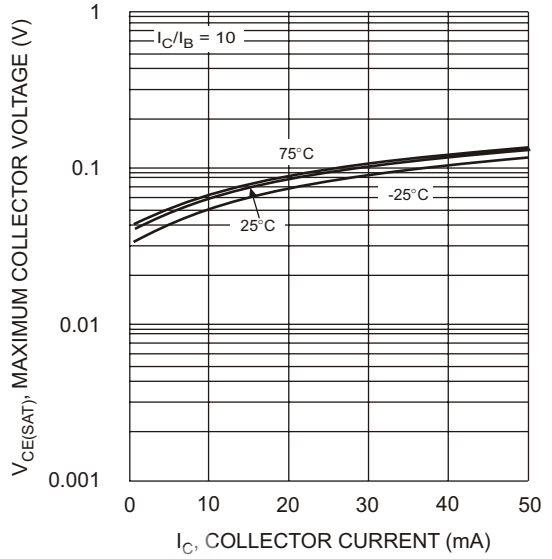


Fig. 2 $V_{CE(SAT)}$ vs. I_C

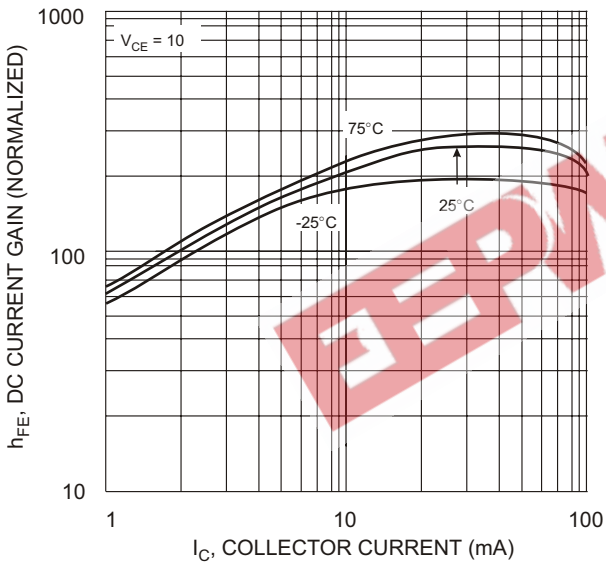


Fig. 3 DC Current Gain

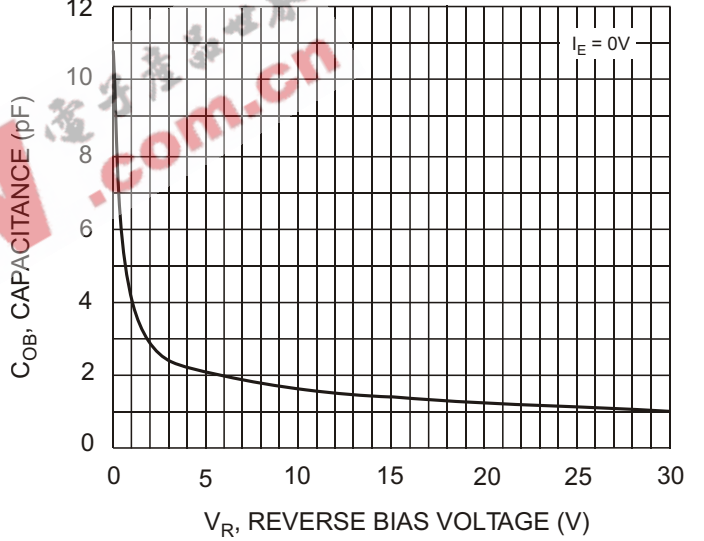


Fig. 4 Output Capacitance

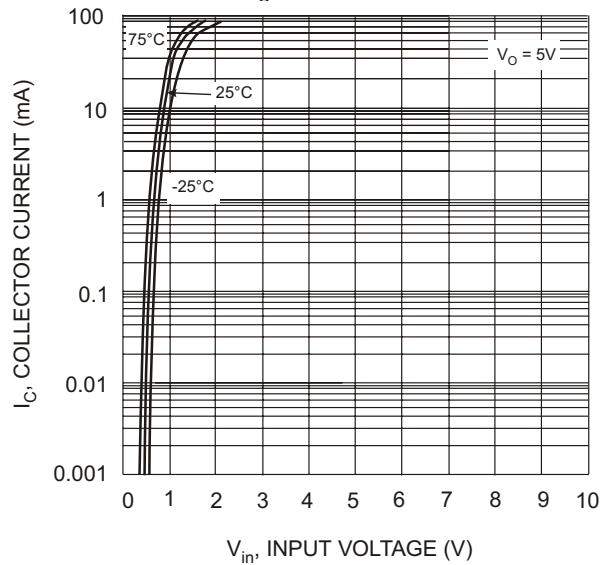


Fig. 5 Collector Current Vs. Input Voltage

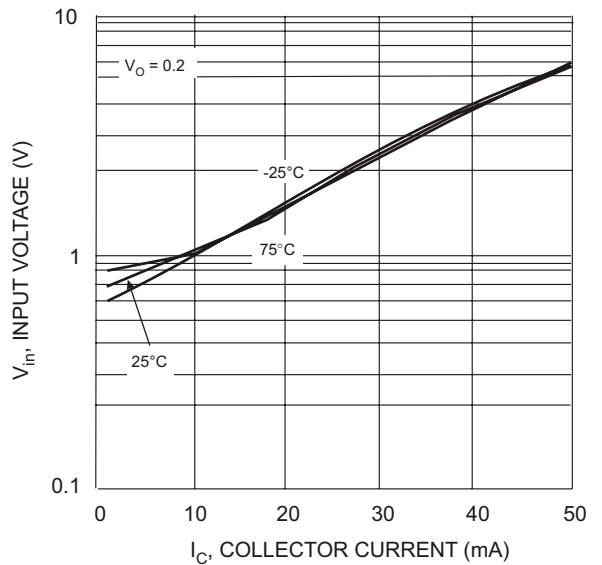


Fig. 6 Input Voltage vs. Collector Current

TYPICAL CURVES - DDA114TU
ONE SECTION

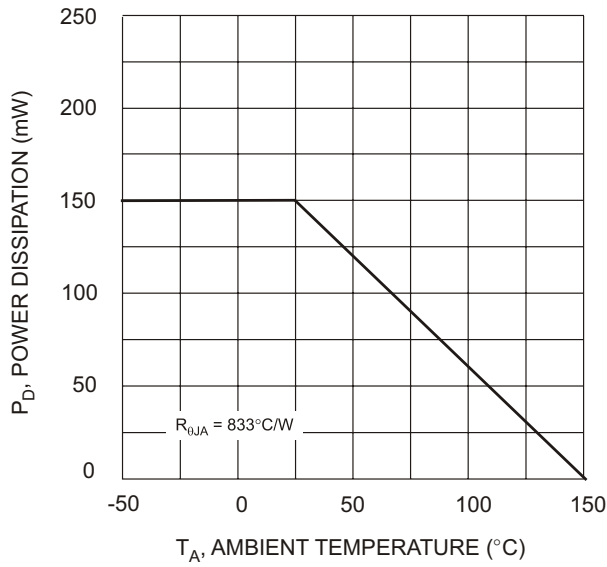


Fig. 1 Derating Curve

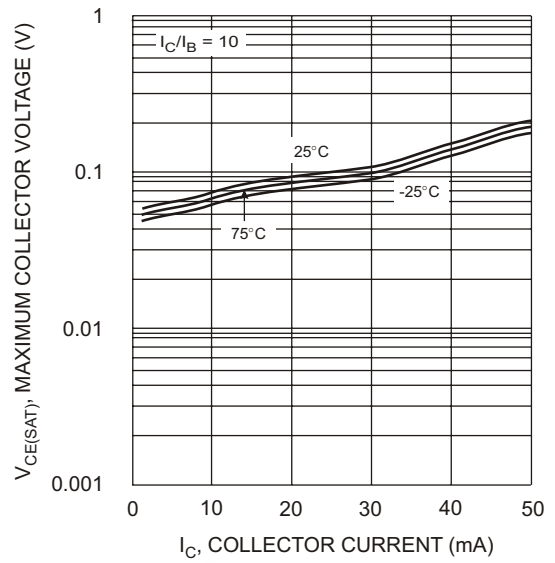


Fig. 2 $V_{CE(SAT)}$ vs. I_C

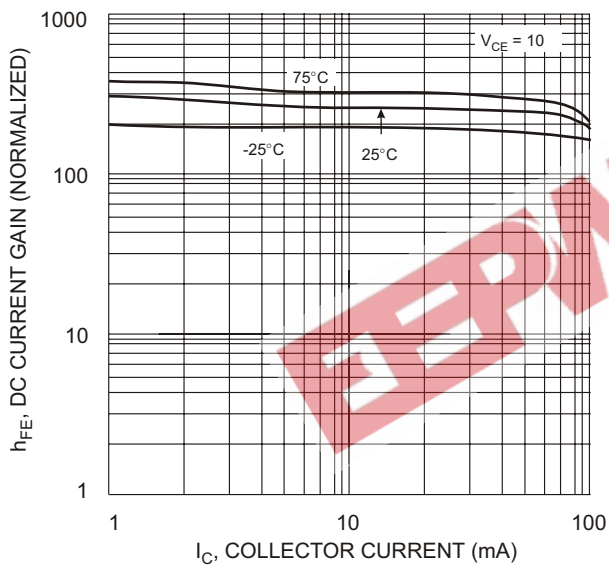


Fig. 3 DC Current Gain

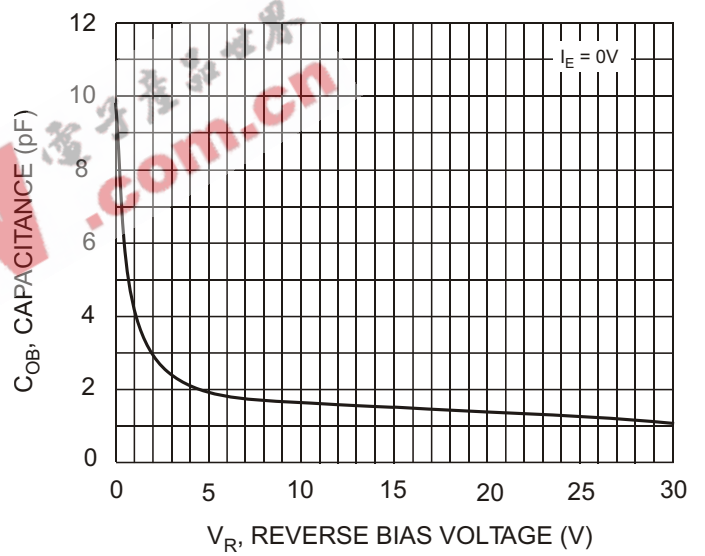


Fig. 4 Output Capacitance

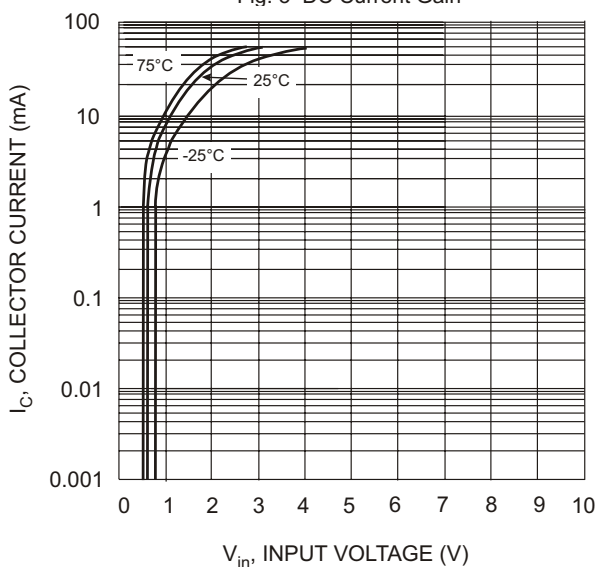


Fig. 5 Collector Current Vs. Input Voltage

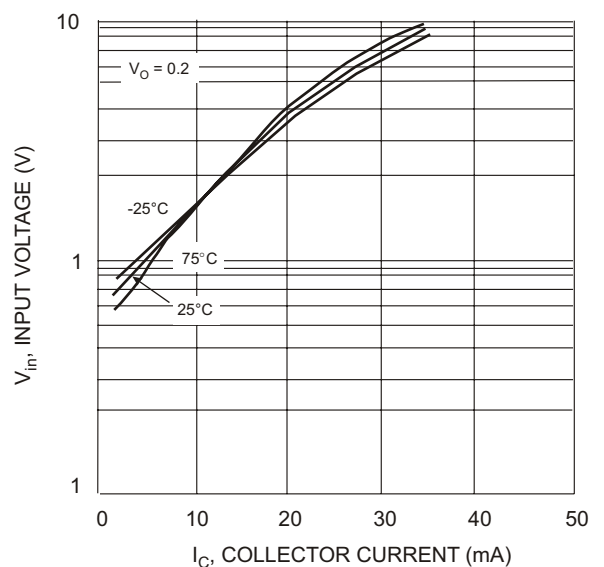


Fig. 6 Input Voltage vs. Collector Current